

Bi-direction Relay Driver 3.5~40V Peak current limiting protection:800mA

1 Description

CN8021, as a bi-direction relay driver circuit, is used to control magnetic latching relays. With a large output capability and ultra-low power consumption, it can be widely used in intelligent electro-meter and other related fields.

CN8021 is available in SOT23-6 and SOP-8 package.

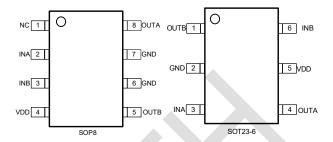
2 Features

- Recommended Supply Voltage Range: 3.5 ~40V
- Peak current limiting protection:800mA
- Ambient Temperature Range: -40 ~+105°C
- Compatible with 3~5V MCU
- Input Signal Anti-Noise Processing

3 Applications

- Smart Circuit Breaker
- Smart Locks
- Smart Water/Gas Meter
- Toys

4 Pinout



5 Ordering information

Product Number	Package	Quantity/Tape
CN8021A	COD 9	2500/Reel
CN8021A	SOP-8	4000/Reel
CN8021B	SOT23-6	3000/Reel

6 Marking

Product Number	Marking
CN9024A	CN8021
CN8021A	YYWW
CNI9024B	CN8021B
CN8021B	YYWW

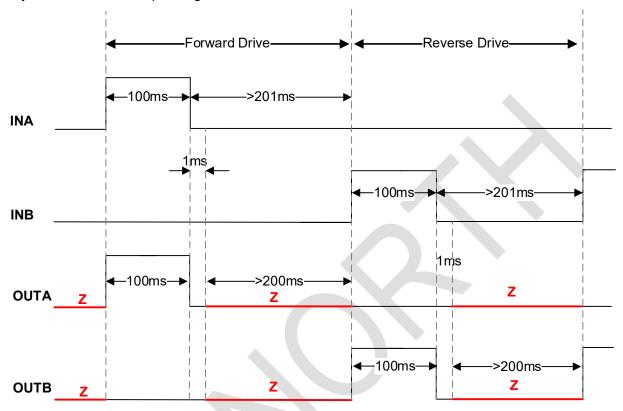
Note: YY=Year WW=Week.

Green (RoHS & HF): CHIPNORTH defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your CHIPNORTH representative directly. Moisture sensitivity level(MSL):3

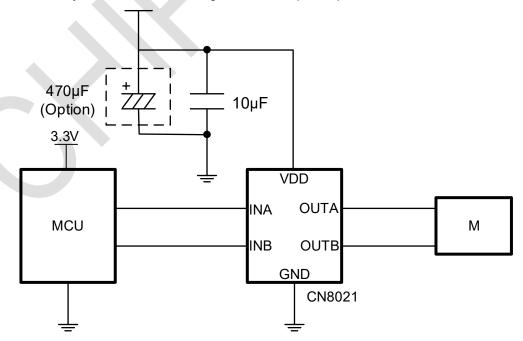


7 Typical Application

CN8021 adopts pulse trigger, as long as the input pulse is triggered according to the function table status, the relay will have the corresponding action.

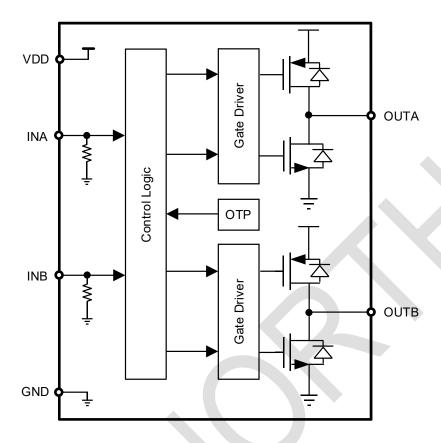


Note: INA and INB are the external drive control logic, OUTA and OUTB are the output waveforms, and Z indicates that the output is in high resistance state. (In this figure, OUTA and OUTB are externally connected to pull-down to ground by default, so that they can be held low when high resistance is present).





8 Block Diagram



9 Logic Function Table

INA	INB	OUTA	OUTB
0	0	Hi-z	Hi-z
0	1	0	1
1	0	1	0
1	1	0	0

10 Pin Descriptions

PIN			Description	
Name	CN8021A	CN8021B	Description	
OUTA	8	4	Output, connect this pin to the motor winding.	
VDD	4	5	Supply Voltage. A capacitor is required to prevent large voltage spikes.	
OUTB	5	1	Output, connect this pin to the motor winding.	
GND	6/7	2	Hot PAD is also GND.	
INA	2	3	Logic input with a large internal pull-down resistor.	
INB	3	6	Logic input with a large internal pull-down resistor.	
NC	1	1	Recommended to be connected to GND.	



11 Specifications

11.1 Absolute Maximum Ratings

Parameter	Value	Units
VDD Supply Voltage Range	-0.4~45	V
INA/INB Supply Voltage Range	- 0.3 ~ 10	V
OUTA/OUTB Supply Voltage Range	-0.4~45	V
Storage Temperature Range	-55~150	°C
Welding Temperature	260 (soldering,10s)	°C

Note:

1.Stress exceeds these ratings listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Expose to absolute-maximum-rated conditions for extended periods may affect device reliability.

2.All voltage values are referenced to the ground terminal

11.2 ESD Ratings

Discharge mode	Standardize	Value	Units
НВМ	JEDECJS-001-2023	±4000	V
CDM	JEDECJS-002-2022	±2000	V

11.3 Recommended Operating Range

Parameter	Symbol	Min.	Max.	Units
Input Voltage	VDD	3.5	40	٧
Input Logic Level	VINx	2.0	7	V
Ambient Temperature Range	TA*	-40	105	°C

^{*}Note: Calculate the maximum ambient temperature based on the specific thermal resistance.

11.4 Thermal Information

Parameter	Package	Value	Unit
θја	SOT23-6	180	°C/W
	SOP-8	120	°C/W

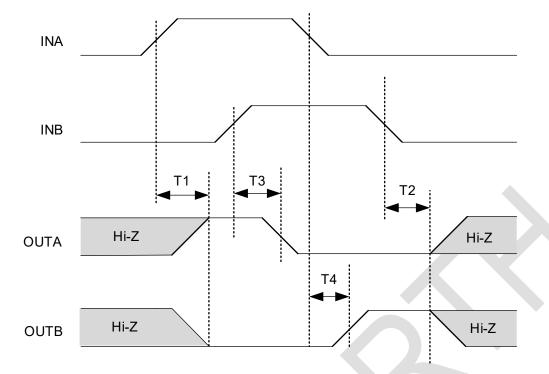


11.5 Electrical Characteristics

Test conditions: TA = 25 °C unless otherwise noted.

Symbol	Description	Conditions	MIN	TYP	MAX	UNIT
VDD	Supply Power Voltage		3.5		40	V
IVDD	Power Down Current	INA=INB=0V, VDD=12V		1.5	3	uA
IB	Input Logic Bias Current	INA=INB=3.3V		8	20	uA
ld	Operating supply current	INA=3V,INB=0V or INA=0V,INB=3V	30	60	100	uA
VTH_H	Input Logic High		2.2			V
VTH_L	Input Logic Low				1.4	V
		VDD=12V, RLOAD=75Ω		7		Ω
		VDD=12V, RLOAD=40Ω		7		Ω
DDC(ON)	Outside On Braintain (BUO : BLO)	VDD=22V, RLOAD=75Ω		7.5		Ω
RDS(ON)		VDD=22V, RLOAD=40Ω		10		Ω
		VDD=30V, RLOAD=75Ω		10		Ω
		VDD=30V, RLOAD=40Ω		10		Ω
TDEGLITCH	Input Noise Blanking Time		0.1		1	μs
Output enable time	Т1			200		ns
Output disable time	Т2			300		ns
Dalasstina	Т3	INB high to OUTA low		250		ns
Delay time	Т4	INA low to OUTB high		250		ns
Anti-reverse excitation	TE			4		
protection time	protection time			1		ms
Thermal shutdown				150		°C
threshold				150		C
Thermal shutdown				30		°C
hysteresis				30		
OCP				8.0		Α

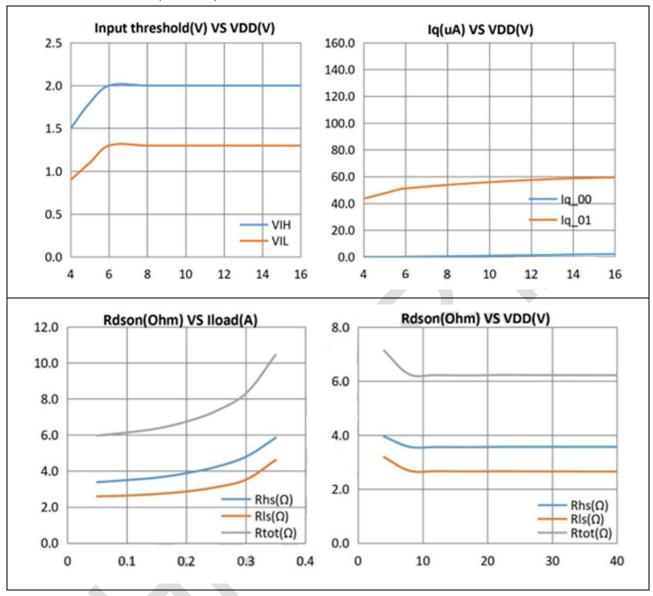






11.6 Characteristics Curve

Test conditions: VDD=12V, TA=25°C, unless otherwise noted.





12 Detailed Description

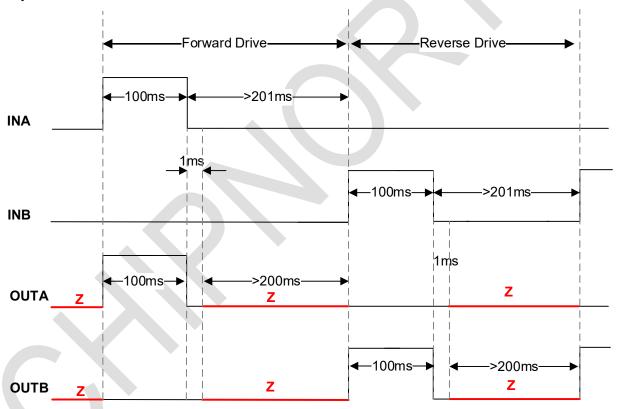
12.1 Overview

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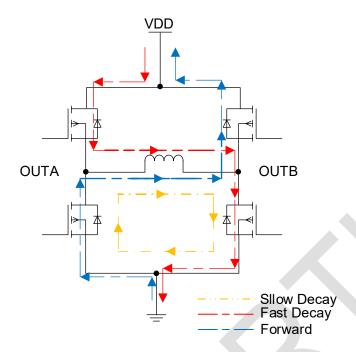
12.2 Unique design

Description: In order to prevent the destructive effect of flyback potential on the chip, CN8021 is designed with the function of anti-flyback potential, through the internal logic configuration of the chip, before INA/INB enters into the "00" high-resistance shutdown state, the actual internal logic control will be added to the additional 1ms of the The internal logic is configured to add an additional 1ms of "11" cutoff before INA/INB enters the "00" high resistance cutoff state. This function can drain the remaining current energy in the relay inductor to earth through the two NMOS, which effectively reduces the chip damage caused by the flyback electromotive force.



Note: INA and INB are the external drive control logic, INA_ACT and INB_ACT are the actual internal control logic, OUTA and OUTB are the output waveforms, and Z indicates that the output is in high resistance state. (In this figure, OUTA and OUTB are externally connected to pull-down to ground by default, so that they can be held low when high resistance is present).

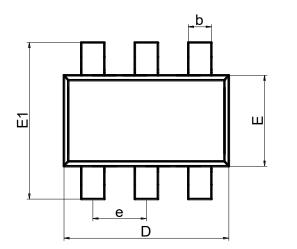


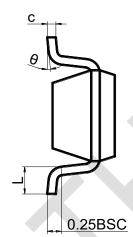


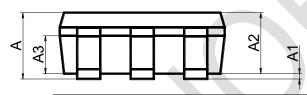


13 Package Information

SOT23-6



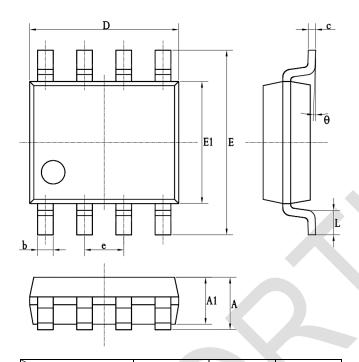




Dimension Symbol	Min (mm)	Nom (mm)	Max (mm)
- Cyllison		, ,	` ,
Α	0.90	1.10	1.40
A2	0.90	1.10	1.30
b	0.30	0.40	0.50
С	0.10	0.15	0.25
D	2.70	2.90	3.10
E	1.50	1.60	1.80
E1	2.50	2.80	3.10
е	-	0.95	-
L	0.20	-	-



SOP-8



Dimension	Min	Nom	Max
Symbol	(mm)	(mm)	(mm)
Α	-	-	1.75
A1	1.25	-	1.55
b	0.33	-	0.51
С	0.17	-	0.26
D	4.70	-	5.10
E	5.80	-	6.20
E1	3.70	-	4.10
е	-	1.27	-
L	0.50	-	0.80
θ	0	-	8°



14 Important Statement

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